TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7W34FU,TC7W34FK

Triple Non-Inverter

The TC7W34 is high speed CMOS BUFFER fabricated with silicon gate CMOS technology.

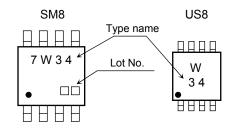
The internal circuit is composed of 2 stage including buffer output, which enable high noise immunity and stable output.

All inputs are equipped with protection circuits against static dichage or transient excess voltage.

Features

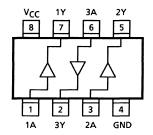
- High speed: $t_{pd} = 6$ ns (typ.) at $V_{CC} = 5$ V
- Low power dissipation: $I_{CC} = 1 \mu A \text{ (max)}$ at $T_a = 25 \text{°C}$
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (min)
- Output drive capability: 10 LSTTL Loads
- Symmetrical output impedance: | I_{OH} | = I_{OL}=4mA(min)
- Balanced propagation delays: $t_{pLH} \approx t_{pHL}$
- Wide operating voltage range: V_{CC} (opr) = 2~5.5 V

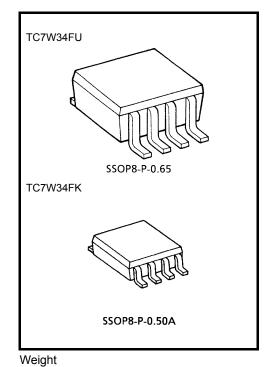
Marking



SSOP8-P-0.65: 0.02 g (typ.) SSOP8-P-0.50A: 0.01 g (typ.)

Pin Assignment (top view)

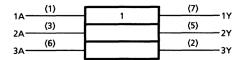




Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Supply voltage range	V _{CC}	-0.5~7.0	V	
DC input voltage	V _{IN}	-0.5~V _{CC} + 0.5	V	
DC output voltage	V _{OUT}	-0.5~V _{CC} + 0.5	V	
Input diode current	l _{IK}	±20	mA	
Output diode current	lok	±20	mA	
DC output current	Гоит	±25	mA	
DC V _{CC} /ground current	Icc	±50	mA	
Dower discipation	D-	300 (SM8)	m\\\/	
Power dissipation	P _D	200 (US8)	mW	
Storage temperature	T _{stg}	-65~150	°C	
Lead temperature (10 s)	TL	260	°C	

Logic Diagram



Truth Table

Α	Υ
L	L
Н	Н

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2.0~6.0	V
Input voltage	V _{IN}	0~V _{CC}	V
Output voltage	V _{OUT}	0~V _{CC}	V
Operating temperature	T _{opr}	-40~85	°C
		0~1000 (V _{CC} = 2.0 V)	
Input rise and fall time	dt/dv	0~500 (V _{CC} = 4.5 V)	ns/V
		0~400 (V _{CC} = 6.0 V)	

Electrical Characteristics

DC Characteristics

Characteristics Symbol					-	Га = 25°C		Ta = -40~85°C		
		Test Condition		V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
		_		2.0	1.5	_	_	1.5	_	V
High-level input voltage	4.5			3.15	_	_	3.15	_		
				6.0	4.2			4.2		
Low-level input V _{IL}		_		2.0	_	_	0.5	_	0.5	٧
	V_{IL}			4.5	_	_	1.35	_	1.35	
Ü				6.0	_	_	1.8	_	1.8	
		VIN = VIH	I _{OH} = -20 μA	2.0	1.9	2.0	_	1.9	_	V
				4.5	4.4	4.5	_	4.4	_	
High-level output voltage	V _{OH}			6.0	5.9	6.0	_	5.9	_	
			$I_{OH} = -4 \text{ mA}$	4.5	4.18	4.31	_	4.13	_	
			$I_{OH} = -5.2 \text{ mA}$	6.0	5.68	5.80	_	5.63	_	
		V _{OL} V _{IN} = V _{IL}	I _{OL} = 20 μA	2.0	_	0.0	0.1	_	0.1	V
				4.5	_	0.0	0.1	_	0.1	
Low-level output voltage VoL	V_{OL}			6.0	_	0.0	0.1	_	0.1	
			I _{OL} = 4 mA	4.5	_	0.17	0.26	_	0.33	
			I _{OL} = 5.2 mA	6.0	_	0.18	0.26	_	0.33	
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		6.0	_	_	±0.1	_	±1.0	μА
Quiescent supply current	Icc	V _{IN} = V _{CC} or GND		6.0	_	_	1.0	_	10.0	μΑ

3 2005-05-18



AC Characteristics ($C_L = 15pF$, $V_{CC} = 5V$, Ta = 25°C)

Characteristics	Symbol	Test Condition		Unit			
Characteristics	Symbol	rest Condition	Min	Тур.	Max	Offic	
Output transition Time	t _{TLH}	_		4	8	ns	
	t_{THL}					115	
Propagation delay time	t _{pLH}	_		6	12	20	
	t_{pHL}					ns	

AC Characteristics ($C_L = 15pF$, Input: $t_r = t_f = 3 \text{ ns}$)

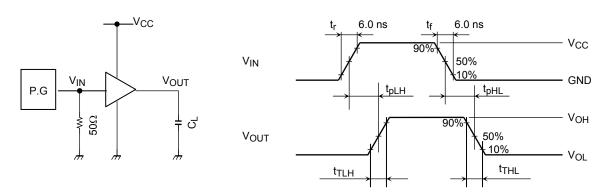
Characteristics Symbol	Symbol	Test Condition		Ta = 25°C			Ta = -40~85°C		Unit
		V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit	
Output transition Time t _{THL}	+		2.0	_	30	75	_	95	
	_	4.5	_	8	15	_	19		
	THL		6.0	_	7	13	_	16	ns
Output transition t _{TLH} Time t _{THL}	+	_	2.0	_	27	75	_	95	115
			4.5		9	15	_	19	
		6.0		8	13	_	16		
Input capacitance	C _{IN}				5	10	_	10	pF
Power dissipation capacitance	C _{PD}		(Note)	_	20	_	_	_	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC/3}$$

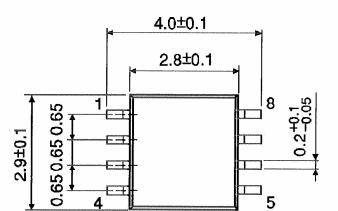
Switching characteristics test circuit

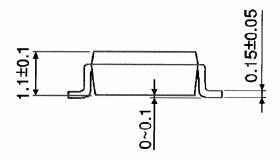


Unit: mm

Package Dimensions

SSOP8-P-0.65



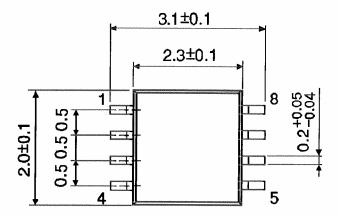


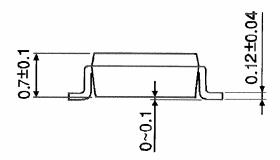
Weight: 0.02 g (typ.)

5 2005-05-18

Package Dimensions

SSOP8-P-0.50A Unit: mm





Weight: 0.01 g (typ.)

6 2005-05-18

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